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To: Examiner Erdem Fazii		From:	From: Leslie S. Szivos, Ph.D.					
Fax:	703 872-9306	Pages	Pages: Tinduding cover page					
Phone		Date:	12/6/2004					
Re:	Your Ref: YOR920030394US1 Application No. 10/696,634 Our Docket: 16963	CC:	CCi					
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Enclo	sed herewith is:	· ·						
1.	Amendment and Response							
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CERTIFICATE OF T Applicant(s): Meikei Ieon	RANSMISSION BY FAC g et al.	SIMILE (37 CFR 1.8)	Y	Docket No. OR920030394US1 (16963)
Application No. 10/696,634	Filing Date October 29, 2003	Examiner Erdem, Fazli		Group Art Unit 2826
Invention: CMOS ON HYBRID SUBST	FRATE WITH DIFFERENT C	RYSTAL ORIENTATIONS U	JSING	SILICON-TO-SILICON
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AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Meikei Ieong et al.					Docket No. YOR920030394US1 (16963)		
Application No. 10/696,634	Filing Date October 29, 2003	Examiner Erdem, Fazli	Customer 23389		Group Art Uni 2826	Confirmation No. 5489	
Invention: CMOS ON HYBR DIRECT WAFER	•	H DIFFERENT CRYST	AL ORIENTATIO	NS U	SING SILICO	N-TO-SILICON	
COMMISSIONER FOR PATENTS:							
		n the above-identified a	•				
		CLAIMS AS AM	ENDED		-		
	CLAIMS REMAINING AFTER AMENDMENT	HIGHEST # PREV. PAID FOR	NUMBER EXTRA CLAIMS PRESENT		RATE	ADDITIONAL FEE	
TOTAL CLAIMS	56 -	58 =	C	×	\$18.00	\$0.00	
INDEP. CLAIMS	4 -	4 =	C	×	\$88.00	\$0.00 \$0.00	
Multiple Dependent Claims (check if applicable)							
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Leslie S. Szivos, Ph.D. Registration No. 39,394 I certify that this document and fee is being deposited on with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450. Signature of Person Mailing Correspondence Typed or Printed Name of Person Mailing Correspondence							

AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Meikel Ieong et al.				Docket No. YOR920030394US1 (16963)				
Application No. 10/696,634	Filing Date October 29, 2003	Examiner Erdem, Fazli	Customer 23389	No.	Group Art Uni	Confirmation No. 5489		
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COMMISSIONER FOR PATENTS:								
		n the above-identified a mitted as shown below	• •					
		CLAIMS AS AM	IENDED					
	CLAIMS REMAINING	HIGHEST#	NUMBER EXTRA			ADDITIONAL		
	AFTER AMENDMENT	PREV. PAID FOR	CLAIMS PRESENT	Ĺ	RATE	FEE		
TOTAL CLAIMS	56 -	58 =	0	x	\$18.00	\$0.00		
INDEP. CLAIMS	4 -	4 =	0	×	\$88.00	\$0.00		
Multiple Depender	Multiple Dependent Claims (check if applicable)							
	TOTAL ADDITIONAL FEE FOR THIS AMENDMENT \$0.00							
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Meikei Ieong et al.

Examiner: Erdem, Fazli

Serial No:

10/696,634

Art Unit: 2826

Filed:

October 29, 2003

Docket: YOR920030394US1 (16963)

Dated:

December 6, 2004

For: CMOS ON HYBRID SUBSTRATE WITH DIFFERENT CRYSTAL ORIENTATIONS USING SILICON-TO SILICON DIRECT WAFER BONDING

Confirmation No.: 5489

Commissioner for Patents United States Patent Office Alexandria, VA 23313-1450

AMENDMENT AND RESPONSE

Sir:

In response to the Office Action dated October 12, 2004, applicants submit the following amendments and remarks for entry of record in the above-identified patent application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this paper is being facsimile transmitted to the Patent and Trademark Office on the date shown below.

Dated: December 6, 2004

Leslie S. Szivos, Ph.D.